
PART NUMBER**RM4136J-ROCV**

**Rochester Electronics
Manufactured Components**

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

RC4136, RM4136, RV4136 QUAD HIGH-PERFORMANCE OPERATIONAL AMPLIFIERS

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- Continuous-Short-Circuit Protection
- Wide Common-Mode and Differential Voltage Ranges
- No Frequency Compensation Required
- Low Power Consumption
- No Latch-Up
- Unity Gain Bandwidth . . . 3 MHz Typ
- Gain and Phase Match Between Amplifiers
- Designed To Be Interchangeable With Raytheon RC4136, RM4136, and RV4136
- Low Noise . . . $8 \text{ nV}/\sqrt{\text{Hz}}$ Typ at 1 kHz

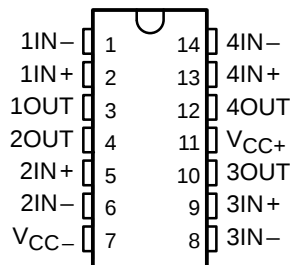
description

The RC4136, RM4136, and RV4136 are quad high-performance operational amplifiers with each amplifier electrically similar to the $\mu\text{A}741$ except that offset null capability is not provided.

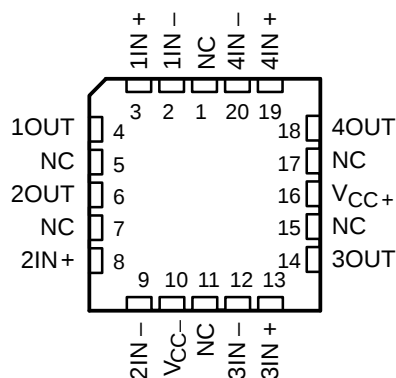
The high common-mode input voltage range and the absence of latch-up make these amplifiers ideal for voltage-follower applications. The devices are short circuit protected and the internal frequency compensation ensures stability without external components.

The RC4136 is characterized for operation from 0°C to 70°C , the RM4136 is characterized for operation over the full military temperature range of -55°C to 125°C , and the RV4136 is characterized for operation from -40°C to 85°C .

RM4136 . . . J OR W PACKAGE
ALL OTHERS . . . D OR N PACKAGE
(TOP VIEW)

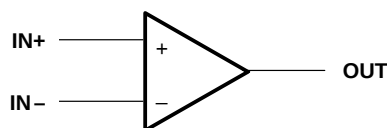


RM4136 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection

symbol (each amplifier)



AVAILABLE OPTIONS

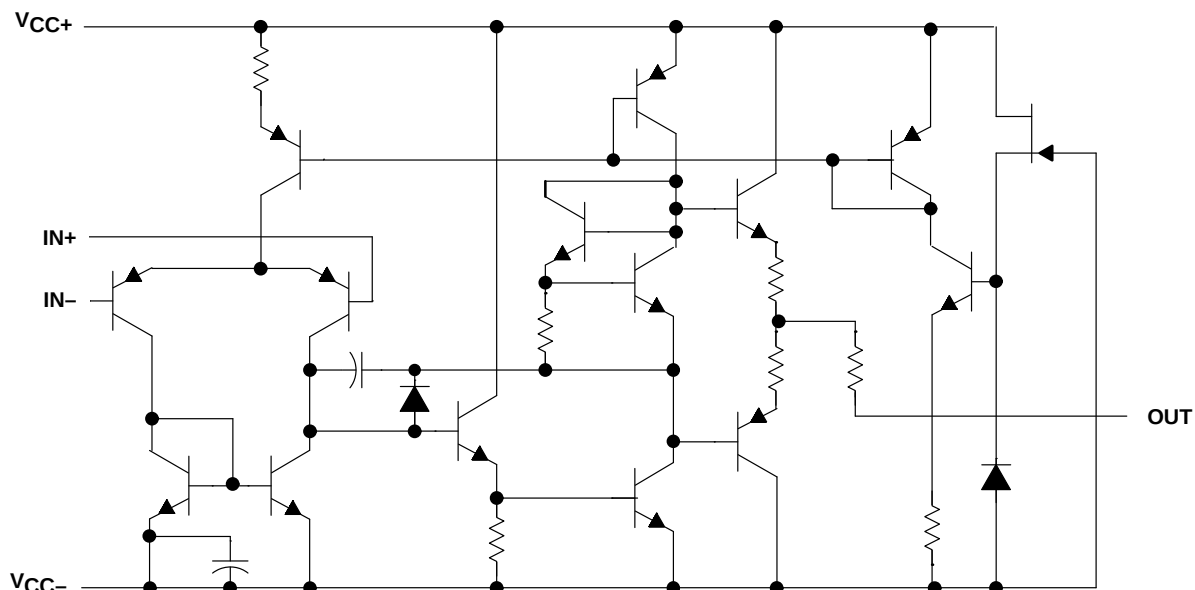
T_A	V_{IOmax} AT 25°C	PACKAGE				
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	FLAT (W)
0°C to 70°C	6 mV	RC4136D	—	—	RC4136N	—
-40°C to 85°C	6 mV	RV4136D	—	—	RV4136N	—
-55°C to 125°C	4 mV	—	RM4136FK	RM4136J	—	RM4136W

The D packages are available taped and reeled. Add the suffix R to the device type (e.g., RC4136DR).

RC4136, RM4136, RV4136 QUAD HIGH-PERFORMANCE OPERATIONAL AMPLIFIERS

SLOS072 – MARCH 1978 – REVISED SEPTEMBER 1990

schematic (each amplifier)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

	RC4136	RM4136	RV4136	UNIT
Supply voltage V_{CC+} (see Note 1)	18	22	18	V
Supply voltage V_{CC-} (see Note 1)	-18	-22	-18	V
Differential input voltage (see Note 2)	± 30	± 30	± 30	V
Input voltage (any input, see Notes 1 and 3)	± 15	± 15	± 15	V
Duration of output short circuit to ground, one amplifier at a time (see Note 4)	unlimited	unlimited	unlimited	
Continuous total dissipation	See Dissipation Rating Table			
Operating free-air temperature range	0 to 70	-55 to 125	-40 to 85	$^{\circ}\text{C}$
Storage temperature range	-65 to 150	-65 to 150	-65 to 150	$^{\circ}\text{C}$
Case temperature for 60 seconds	FK package			
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J or W package			
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or N package			

NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 2. Differential voltages are at IN+ with respect to IN- .
 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
 4. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^{\circ}\text{C}$ POWER RATING	DERATING FACTOR	DERATE ABOVE T_A	$T_A = 70^{\circ}\text{C}$ POWER RATING	$T_A = 85^{\circ}\text{C}$ POWER RATING	$T_A = 125^{\circ}\text{C}$ POWER RATING
D	800 mW	7.6 mW/ $^{\circ}\text{C}$	45 $^{\circ}\text{C}$	608 mW	494 mW	—
FK	800 mW	11.0 mW/ $^{\circ}\text{C}$	77 $^{\circ}\text{C}$	800 mW	715 mW	275 mW
J	800 mW	11.0 mW/ $^{\circ}\text{C}$	77 $^{\circ}\text{C}$	800 mW	715 mW	275 mW
N	800 mW	9.2 mW/ $^{\circ}\text{C}$	63 $^{\circ}\text{C}$	736 mW	598 mW	—
W	800 mW	8.0 mW/ $^{\circ}\text{C}$	50 $^{\circ}\text{C}$	640 mW	520 mW	200 mW

RC4136, RM4136, RV4136

QUAD HIGH-PERFORMANCE OPERATIONAL AMPLIFIERS

SLOS072 – MARCH 1978 – REVISED SEPTEMBER 1990

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V_{CC+}	5	15	V
Supply voltage, V_{CC-}	-5	-15	V

electrical characteristics at specified free-air temperature, $V_{CC+} = 15$ V, $V_{CC-} = -15$ V

PARAMETER		TEST CONDITIONS†		RC4136			RM4136			RV4136			UNIT			
				MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX				
V _{IL}	Input offset voltage	V _O = 0	25°C	0.5		6	0.5		4	0.5		6	mV			
			Full range			7.5			6			7.5				
I _{IO}	Input offset current	V _O = 0	25°C	5		200	5		1.50	5		200	nA			
			Full range			300			500			500				
I _{IB}	Input bias current	V _O = 0	25°C	140		500	140		400	140		500	nA			
			Full range			800			1500			1500				
V _i	Input voltage range		25°C	±12	±14		±12	±14		±12	±14		V			
V _{OM}	Maximum peak output voltage swing	R _L = 10 kΩ	25°C	±12	±14		±12	±14		±12	±14		V			
		R _L = 2 kΩ	25°C	±10	±13		±10	±13		±10	±13					
		R _L ≥ 2 kΩ	Full range	±10			±10			±10						
A _{VD}	Large-signal differential voltage amplification	V _O = ±10 V, R _L ≥ 2 kΩ	25°C	20	300		50	350		20	300		V/mV			
			Full range	15			25			15						
B ₁	Unity-gain bandwidth		25°C	3			3.5			3		MHz				
r _i	Input resistance		25°C	0.3*	5		0.3*	5		0.3*	5		MΩ			
CMRR	Common-mode rejection ratio	V _O = 0, R _S = 50 Ω	25°C	70	90		70	90		70	90		dB			
k _{SVS}	Supply voltage sensitivity (ΔV _{IO} /ΔV _{CC})	V _{CC} = ±9 V to ±15 V, V _O = 0	25°C		30		150	30		150	30		150	μV/V		
V _n	Equivalent input noise voltage (closed-loop)	A _{VD} = 100, BW = 1 Hz, f = 1 kHz, R _S = 100 Ω	25°C		8			8			8		nV√Hz			
I _{CC}	Supply current (all four amplifiers)	V _O = 0, No load	25°C		5		11.3		5		11.3		5		11.3	mA
			MIN T _A		6		13.7		6		13.3		6		13.7	
			MAX T _A		4.5		10		4.5		10		4.5		10	
P _D	Total power dissipation (all four amplifiers)	V _O = 0, No load	25°C		150		340		150		340		150		340	mW
			MIN T _A		180		400		180		400		180		400	
			MAX T _A		135		300		135		300		135		300	
	Crosstalk attenuation (V _{O1} /V _{O2})	A _{VD} = 100, f = 10 kHz, R _S = 1 kΩ	25°C		105			105			105			dB		

* This parameter is not production tested.

† All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range is 0°C to 70°C for RC4136, -55°C to 125°C for RM4136, and -40°C to 85°C for RV4136. Minimum T_A is 0°C for RC4136, -55°C for RM4136, and -40°C for RV4136. Maximum T_A is 70°C for RC4136, 125°C for RM4136, and 85°C for RV4136.



RC4136, RM4136, RV4136

QUAD HIGH-PERFORMANCE OPERATIONAL AMPLIFIERS

SLOS072 – MARCH 1978 – REVISED SEPTEMBER 1990

operating characteristics, $V_{CC+} = 15\text{ V}$, $V_{CC-} = -15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		RC4136, RV4136			RM4136			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
t _r	Rise time	V _I = 20 mV, C _L = 100 pF	R _L = 2 kΩ,	0.13			0.13			μs
	Overshoot factor			5%			5%			
SR	Slew rate at unity gain	V _I = 10 V, C _L = 100 pF	R _L = 2 kΩ,	1.7			1.7			V/μs

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